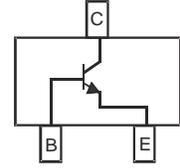




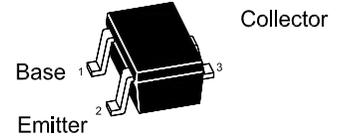
MMSTA05/MMSTA06 NPN SMALL SIGNAL SURFACE MOUNT TRANSISTOR

Features

- Epitaxial Planar Die Construction
- Complementary PNP Type Available (MMSTA55/MMSTA56)
- Ideal for Medium Power Amplification and Switching
- Ultra-Small Surface Mount Package



Marking K1H = MMSTA05
K1G = MMSTA06



SOT-323

Maximum Ratings @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	MMSTA05	MMSTA06	Unit
Collector-Base Voltage	V_{CBO}	60	80	V
Collector-Emitter Voltage	V_{CEO}	60	80	V
Emitter-Base Voltage	V_{EBO}	4.0		V
Collector Current - Continuous (Note 1)	I_C	500		mA
Power Dissipation (Note 1)	P_d	200		mW
Thermal Resistance, Junction to Ambient (Note 1)	$R_{\theta JA}$	625		$^\circ\text{C}/\text{W}$
Operating and Storage Temperature Range	T_j, T_{STG}	-55 to +150		$^\circ\text{C}$

Electrical Characteristics @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 5)					
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	60 80	—	V	$I_C = 100\mu\text{A}, I_E = 0$
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	60 80	—	V	$I_C = 1.0\text{mA}, I_B = 0$
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	4.0	—	V	$I_E = 100\mu\text{A}, I_C = 0$
Collector Cutoff Current	I_{CBO}	—	100	nA	$V_{CB} = 60\text{V}, I_E = 0$ $V_{CB} = 80\text{V}, I_E = 0$
Collector Cutoff Current	I_{CES}	—	100	nA	$V_{CE} = 60\text{V}, I_{B0} = 0\text{V}$ $V_{CE} = 80\text{V}, I_{B0} = 0\text{V}$
ON CHARACTERISTICS (Note 5)					
DC Current Gain	h_{FE}	100	—	—	$I_C = 10\text{mA}, V_{CE} = 1.0\text{V}$ $I_C = 100\text{mA}, V_{CE} = 1.0\text{V}$
Collector-Emitter Saturation Voltage	$V_{CE(SAT)}$	—	0.25	V	$I_C = 100\text{mA}, I_B = 10\text{mA}$
Base-Emitter Saturation Voltage	$V_{BE(SAT)}$	—	1.2	V	$I_C = 100\text{mA}, V_{CE} = 1.0\text{V}$
SMALL SIGNAL CHARACTERISTICS					
Current Gain-Bandwidth Product	f_T	100	—	MHz	$V_{CE} = 2.0\text{V}, I_C = 10\text{mA}, f = 100\text{MHz}$

Notes: 1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch;

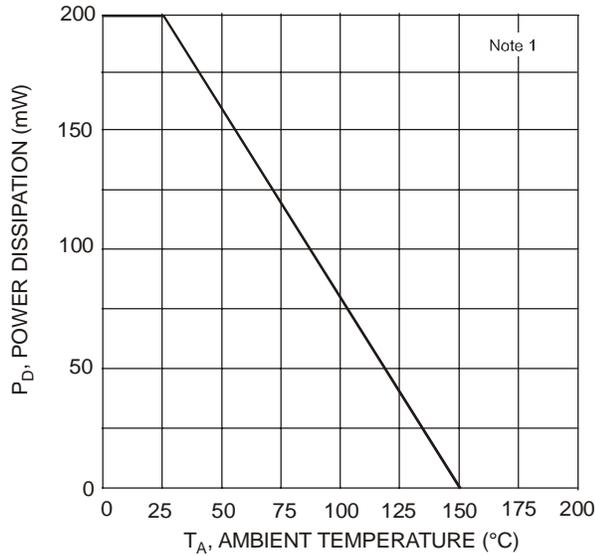


Fig. 1, Max Power Dissipation vs. Ambient Temperature

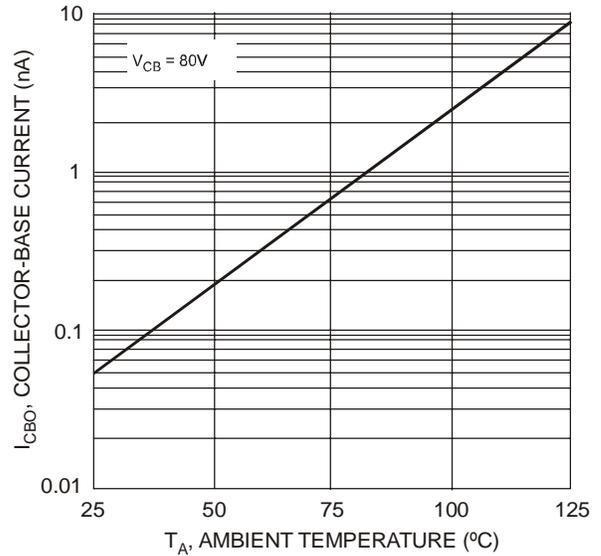


Fig. 2 Typical Collector-Cutoff Current vs. Ambient Temperature

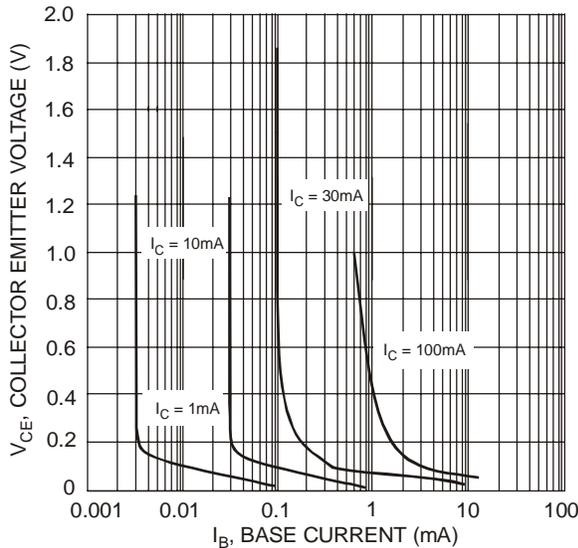


Fig. 3 Typical Collector Saturation Region

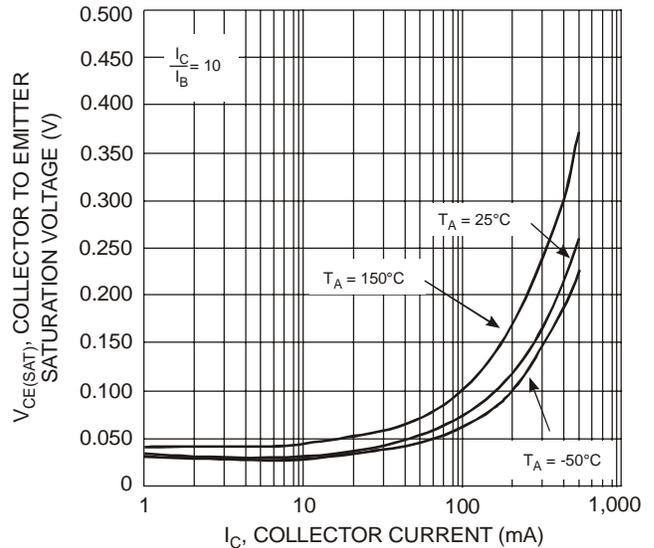


Fig. 4 Collector Emitter Saturation Voltage vs. Collector Current

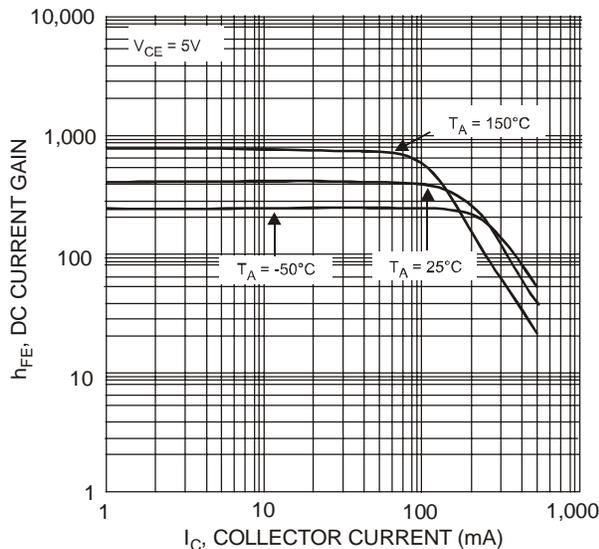


Fig. 5, DC Current Gain vs. Collector Current

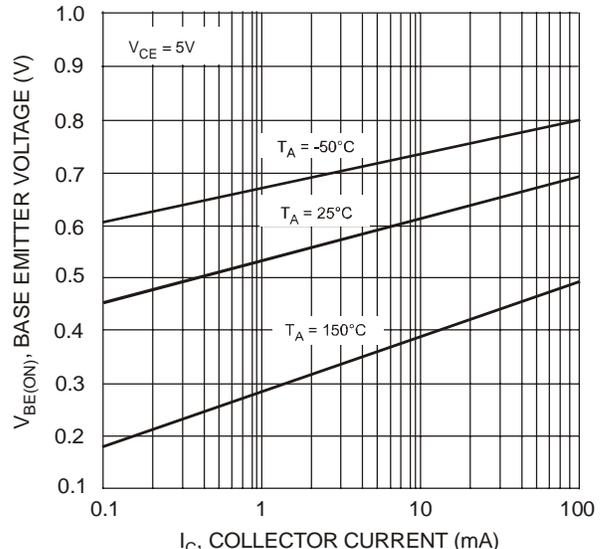


Fig. 6, Base Emitter Voltage vs. Collector Current

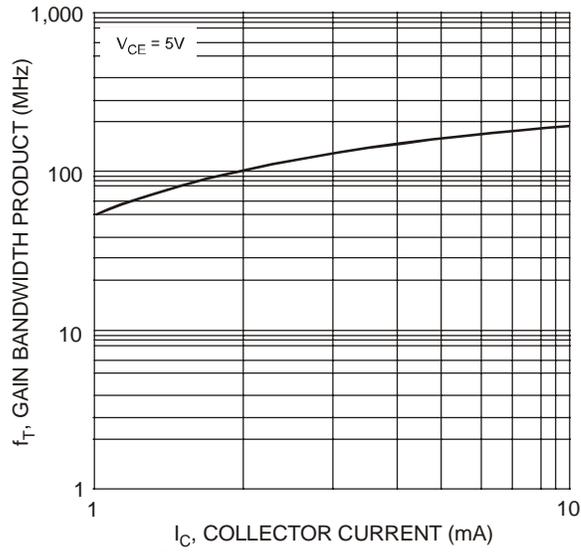
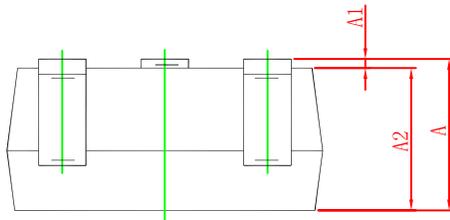
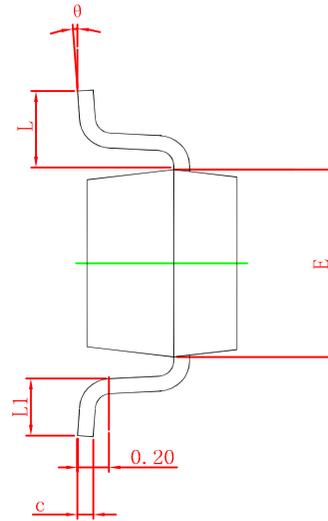
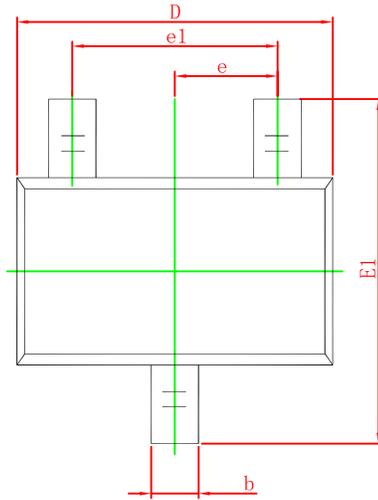


Fig. 7, Gain Bandwidth Product vs Collector Current



SOT-323 PACKAGE OUTLINE DIMENSIONS



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.900	1.100	0.035	0.043
A1	0.000	0.100	0.000	0.004
A2	0.900	1.000	0.035	0.039
b	0.200	0.400	0.008	0.016
c	0.080	0.150	0.003	0.006
D	2.000	2.200	0.079	0.087
E	1.150	1.350	0.045	0.053
E1	2.150	2.450	0.085	0.096
e	0.650 TYP.		0.026 TYP.	
e1	1.200	1.400	0.047	0.055
L	0.525 REF.		0.021 REF.	
L1	0.260	0.460	0.010	0.018
θ	0°	8°	0°	8°